

One-pot synthesis of high-quality Cd:CuInS₂ quaternary quantum dots as sensitizers for photovoltaic cell

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Supplementary Information

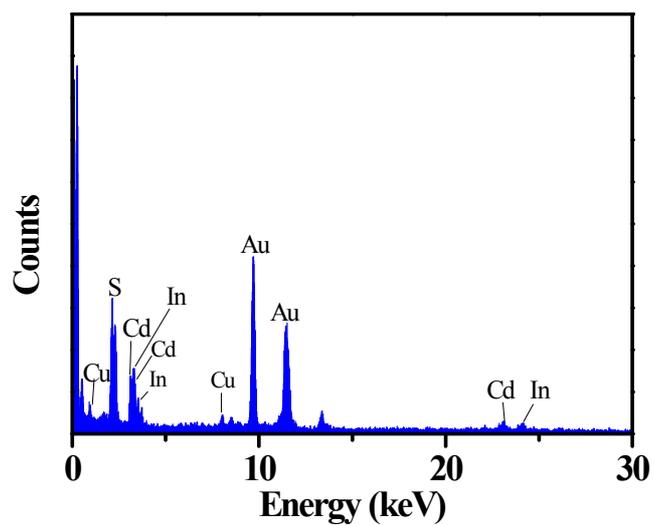


Figure S1. EDS spectra of Cd:CuInS₂ *q*-QDs. The Au signals are owing to the Au TEM grid.

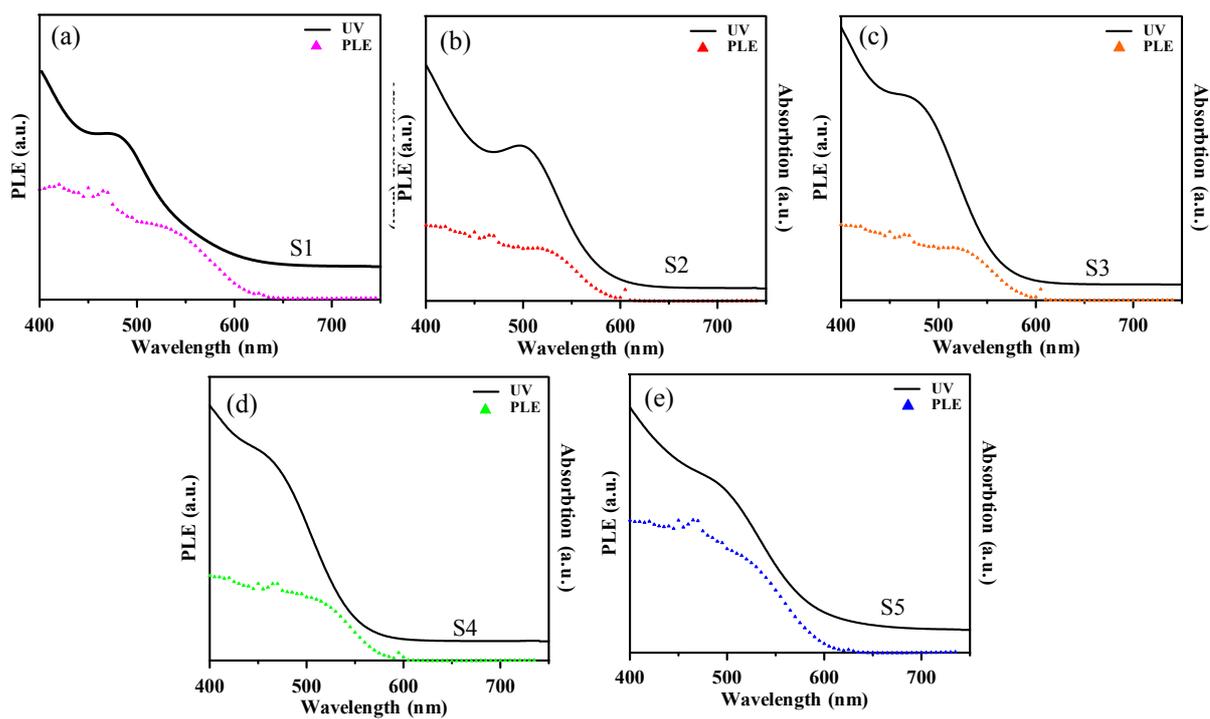


Figure S2. Comparison of the absorption (solid line) and photoluminescence emission (dot line) spectra of samples S1–S5.

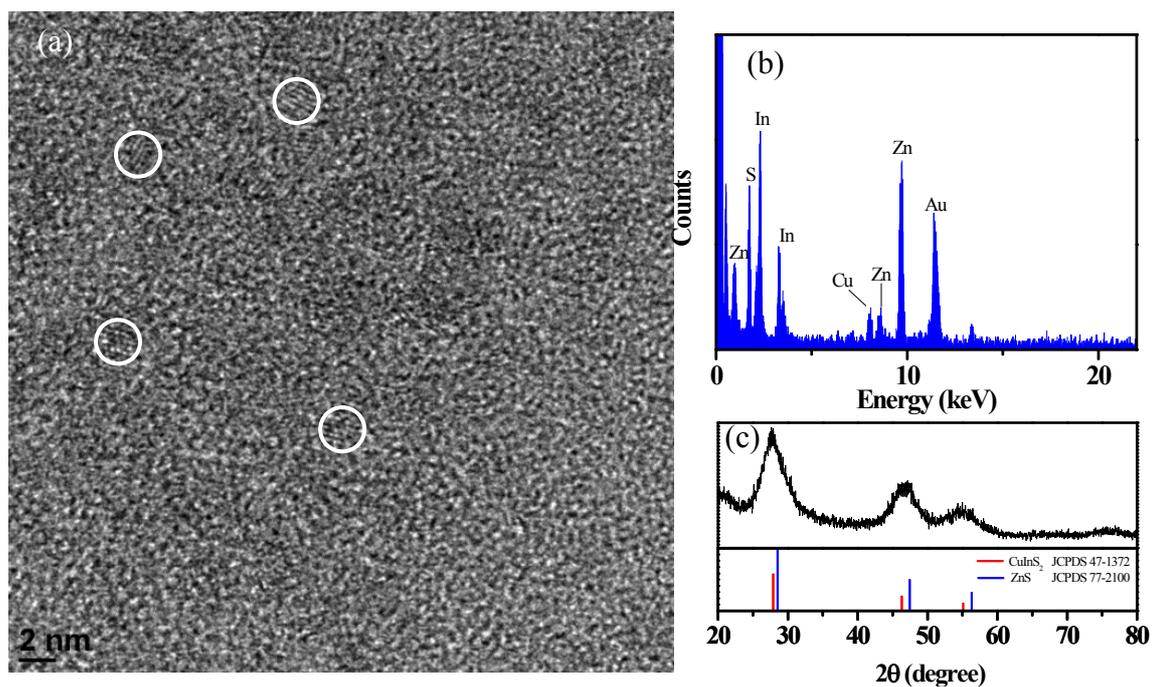


Figure S3. (a) HRTEM image, (b) EDS spectrum, and (c) XRD of Zn:CuInS₂ *q*-QDs. The white circles show the location of *q*-QDs. The Au signals are owing to the Au TEM grid.

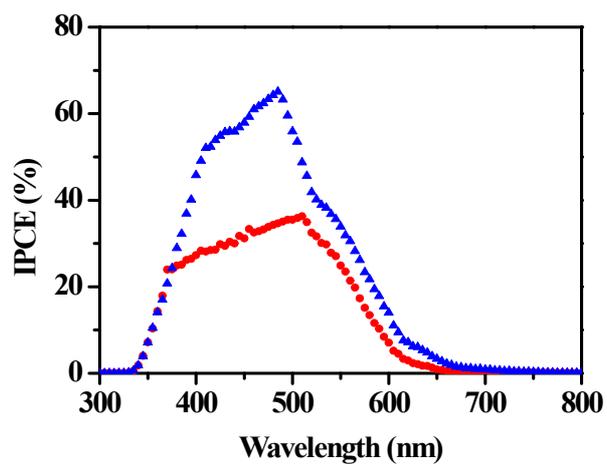


Figure S4. IPCE curves of Cd:CuInS₂/CdS(3) (red dot) and Cd:CuInS₂/CdSe(4) (blue dot) based QDSSC.